TECHNICAL DATA DATA SHEET 4052, REV. B

HERMETIC POWER SCHOTTKY RECTIFIER Low Forward Voltage

DESCRIPTION: A 100-VOLT, 30/45 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-254 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25$ °C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (@ Tc=100 °C) (Single, Doubler)	lo	30	Amps
MAXIMUM DC OUTPUT CURRENT (@ T _C =100 °C) (Common Cathode, Common Anode)	lo	45	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=8.3ms, Sine)	I _{FSM}	200	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	Ст	1200	pF
MAXIMUM THERMAL RESISTANCE (PER LEG) (Single, Common Cathode, Common Anode, Doubler)	R _θ JC	1.5	°C/W
MAXIMUM OPERATING TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C
MAXIMUM STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C

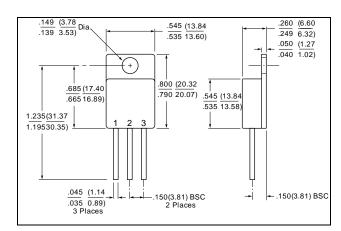
ELECTRICAL CHARACTERISTICS

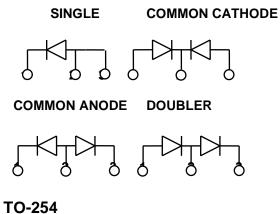
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 30 Amps)			
T _J = 25 °C	V_{f}	1.01	Volts
T _J = 125 °C	,	0.85	
MAXIMUM REVERSE CURRENT (Ir @ 100 V PIV)			
T _J = 25 °C	l _r	0.75	mA
T _J = 125 °C	,	15	

SENSITRON

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Mechanical Dimensions: In inches / mm





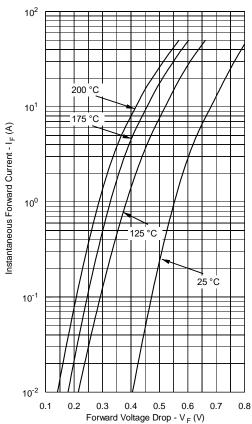
PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	CATHODE/ ANODE	CATHODE

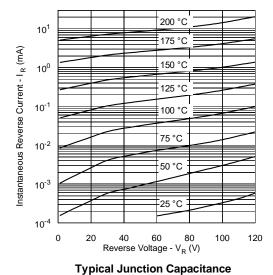
Curves shown are for bare die only.

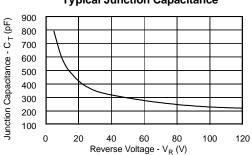


Typical Forward Characteristics

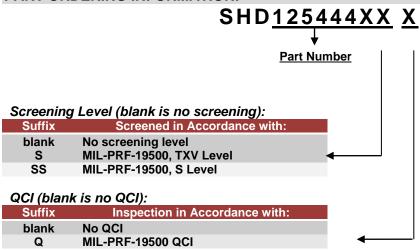


Typical Reverse Characteristics





PART ORDERING INFORMATION:



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